EAST Search History

EAST Search History (Prior Art)

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
		substrate and material and and wir$5 resin and reflect $3 and (LED diode chip semiconductor) and insulat $3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/09/24 08:49
L1	2	"20020001192"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/09/24 08:27
L2	10	362/612.ccls. and @ad<"20040326" and resin and reflect$3 and (LED diode chip semiconductor) and insulat $3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/09/24 08:33
L3	4	362/230.ccls. and @ad<"20040326" and resin and reflect$3 and (LED diode chip semiconductor) and insulat $3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/09/24 08:37
L4	12	362/231.ccls. and @ad<"20040326" and resin and reflect$3 and (LED diode chip semiconductor) and insulat $3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/09/24 08:37
L5	11	362/249.02.ccls. and @ad<"20040326" and resin and reflect$3 and (LED diode chip semiconductor) and insulat $3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/09/24 08:38
L6	2	"6930332".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/09/24 08:41
L7	7	362/249.01.ccls. and @ad<"20040326" and resin and reflect$3 and (LED diode chip semiconductor) and insulat $3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/09/24 08:43

L8	155	257/79.ccls. and @ad<"20040326" and resin and reflect$3 and (LED diode chip semiconductor) and insulat$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/09/24 08:44
L9	361481	substrate and material and wir$5 resin and reflect$3 and (LED diode chip semiconductor) and insulat$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/09/24 08:50
L10	19296	substrate and material and wir$5 and resin and reflect$3 and (LED diode chip semiconductor) and insulat$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/09/24 08:50
L11	9697	l10 and @ad<"20040326"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/09/24 08:50
L12	6709	l11 and mount$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/09/24 08:51
L13	2795	l12 and adher$5	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/09/24 08:51
L14	123874	"362"/$.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/09/24 08:52
L15	156	l12 and l14	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/09/24 08:52
L16	281	257/98.ccls. and @ad<"20040326" and resin and reflect$3 and (LED diode chip semiconductor) and insulat$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/09/24 09:06
L17	142	257/100.ccls. and @ad<"20040326" and resin and reflect$3 and (LED diode chip semiconductor) and insulat$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/09/24 09:13

L18	102	257/103.ccls. and @ad<"20040326" and resin and reflect$3 and (LED diode chip semiconductor) and insulat$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/09/24 09:25
L19	75	(substrate and material and wir$5 and resin and reflect$3 and (LED diode chip semiconductor) and insulat$3).clm.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/09/24 09:40
L21	7	362/227.ccls. and @ad<"20040326" and resin and reflect$3 and (LED diode chip semiconductor) and insulat$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/09/24 09:46
L22	7	362/237.ccls. and @ad<"20040326" and resin and reflect$3 and (LED diode chip semiconductor) and insulat$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/09/24 09:46

EAST Search History (Interference)

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L20	24	(substrate and material and wir$5 and resin and reflect$3 and (LED diode chip semiconductor) and insulat$3).clm.	USPAT; UPAD	OR	ON	2009/09/24 09:44

9/24/09 9:48:27 AM
C:\ Documents and Settings\ btruong\ My Documents\ EAST\ Workspaces\ illumination.wsp